



DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	Rds(on)	ID @TA = +25°C
20V	0.45Ω @V _{GS} = $4.5V$	0.92A
200	0.6Ω @Vgs = 2.5V	0.8A

Description

This new generation MOSFET has been designed to minimize the onstate resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Battery operated systems and solid-state relays
- Drivers: relays, solenoids, lamps, hammers, displays, memories, transistors, etc.
- Power supply converter circuits

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage V_{GS(TH)} < 1V
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)

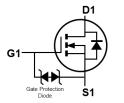


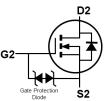


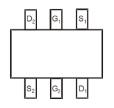
Top View



Bottom View







Internal Schematic

Top View

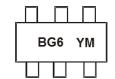
Ordering Information (Note 4)

Dort Number	Deskore	Packing		
Part Number	Package	Qty.	Carrier	
DMN2710UV-7	SOT563	3,000	Tape & Reel	

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



BG6 = Product Type Marking Code YM = Date Code Marking \overline{Y} = Year (ex: J = 2022) M = Month (ex. 9 = September)

Date Code Key

Year	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	J	K	L	М	N	0	Р	R	S	Т	U	V
Month	lan	Eab	Mor	Anr	Mov	lun	11	Διια	Sen	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	20	V	
Gate-Source Voltage		V _{GSS}	±6	V
Continuous Drain Current (Note 6) V _{GS} = 4.5V	ID	0.92 0.74	А	
Maximum Continuous Body Diode Forward Current (Note	Is	0.54	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	5.5	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	$T_A = +25$ °C	PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	251	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	0.58	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	216	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

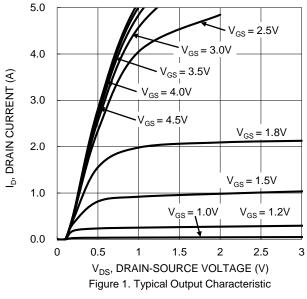
Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

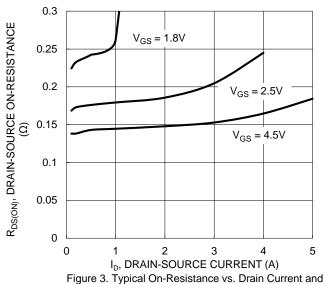
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						•
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current @T _C = +25°C	IDSS	_	_	100	nA	V _{DS} = 20V, V _{GS} = 0V
Gate-Source Leakage	Igss	_	_	±1.0	μΑ	$V_{GS} = \pm 4.5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
			0.13	0.45		V _G S = 4.5V, I _D = 600mA
Static Drain-Source On-Resistance	RDS(ON)	_	0.16	0.6	Ω	$V_{GS} = 2.5V, I_{D} = 500mA$
			0.2	0.75		V _G S = 1.8V, I _D = 350mA
Diode Forward Voltage (Note 7)	VsD	_	0.7	1.2	V	V _G S = 0V, I _S = 150mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	42	_	pF	
Output Capacitance	Coss	_	13	_	pF	V _{DS} = 16V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	6.5	_	pF	-1 = 1.0WHZ
Total Gate Charge		_	0.6	_	nC	
Gate-Source Charge	Qgs	_	0.1	_	nC	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 250mA
Gate-Drain Charge		_	0.1	_	nC	7 ID = 230ITIA
Turn-On Delay Time	t _D (ON)	_	4.9	_	ns	
Turn-On Rise Time		_	3.1	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time		_	386	_	ns	$R_L = 47\Omega$, $R_G = 10\Omega$
Turn-Off Fall Time	t _F	_	174	_	ns	

Notes:

- 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to production testing.







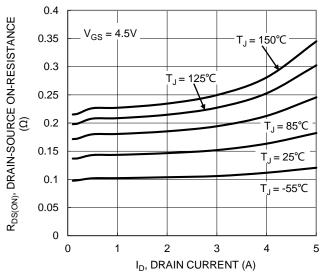
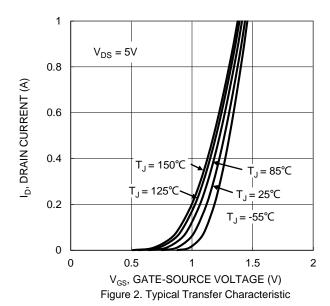
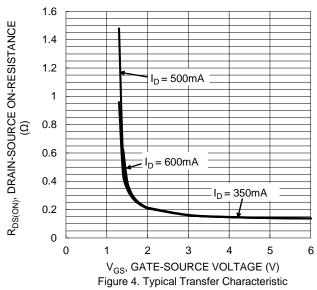


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

Gate Voltage





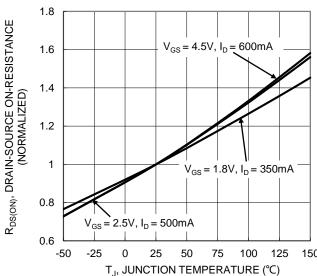


Figure 6. On-Resistance Variation with Junction Temperature

DMN2710UV



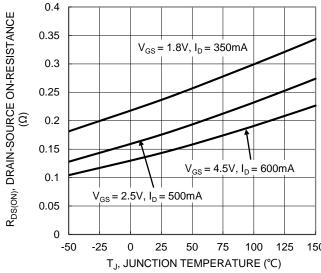
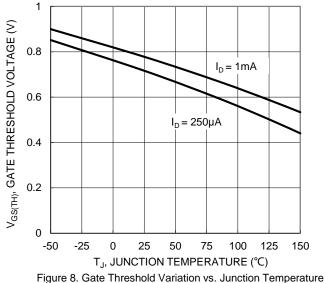
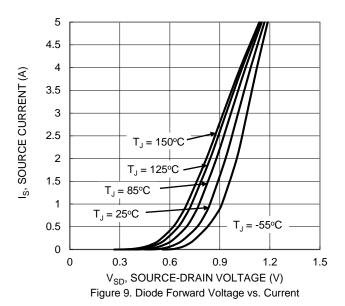
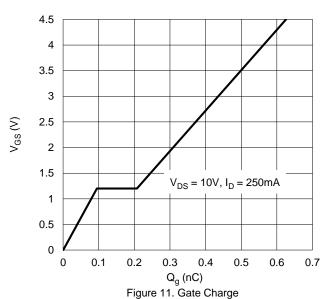
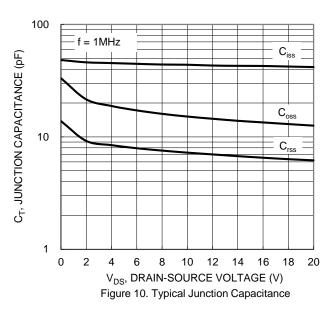


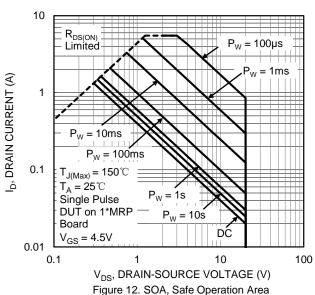
Figure 7. On-Resistance Variation with Junction Temperature













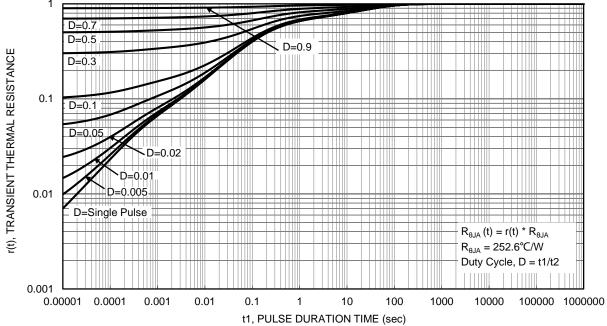


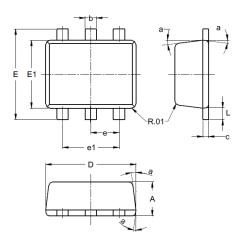
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563

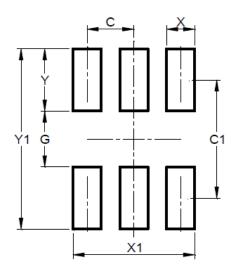


SOT563						
Dim	Min	Max	Тур			
Α	0.55	0.60				
b	0.15	0.30	0.20			
С	0.10	0.18	0.11			
D	1.50	1.70	1.60			
E	1.55	1.70	1.60			
E1	1.10	1.25	1.20			
е			0.50			
e1	0.90	1.10	1.00			
L	0.10	0.30	0.20			
а	8°	9°	7°			
All	All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT563



Dimensions	Value (in mm)
С	0.500
C1	1.270
G	0.600
Х	0.300
X1	1.300
Υ	0.670
Y1	1 940



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